MMG100D120B6HN

1200V 100A IGBT Module

July 20113 Tm 0 g -Cs6 cs2 1 0 0scn 17.8290 0 TD -.0015 Tc[

- High short circuit capability,self limiting short circuit current
- IGBT CHIP(Trench and Fieldstop technology)
- $V_{CE(sat)}$ with positive temperature coefficient
- FastTT2 1 4ET2 V2 8lm7(8.1an 8l(d ss)-7.t)10apilcircur

ELECTRICAL AND THER MAL CHARACTERISTICS T_C=25°C unless otherwise specified

MODULE CHARACTERISTICS

0 50

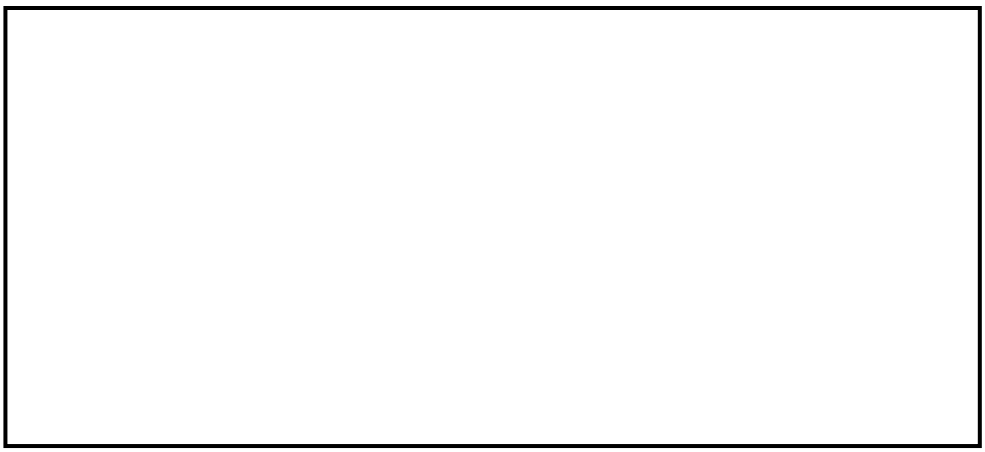
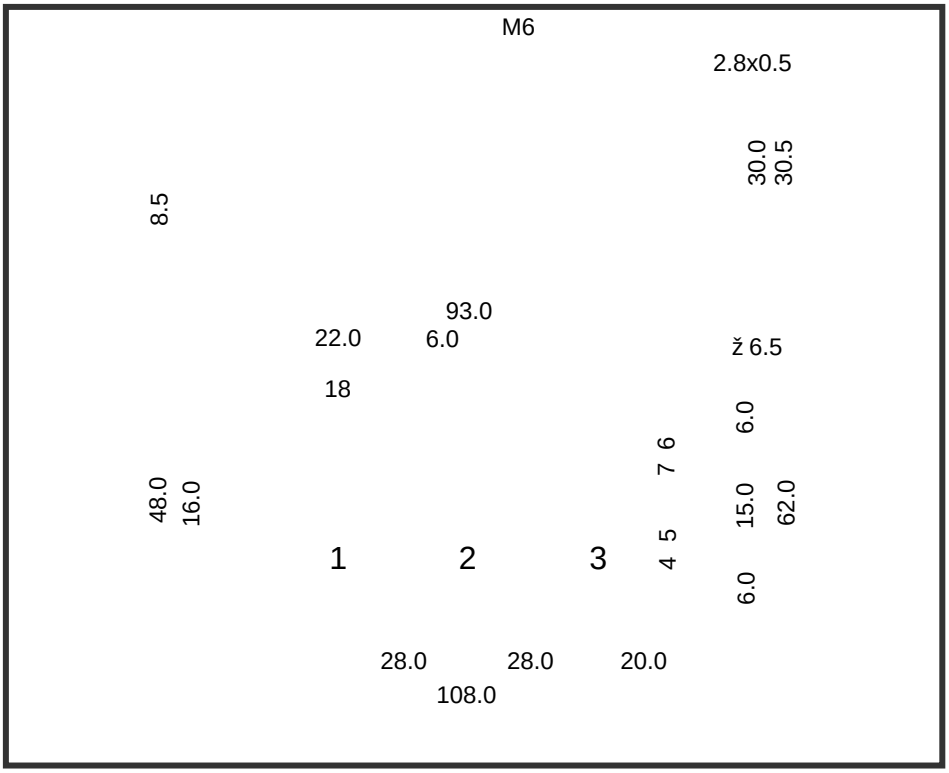


Figure11. Circuit Diagram



Dimensions (mm)
Figure12. Package Outline